# NSN 5961-01-206-4136

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Inclosure Material:

Ceramic and metal

**Overall Length:** 

0.078 inches

**Overall Height:** 

0.039 inches

Overall Width:

0.078 inches

Internal Configuration:

Junction contact

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

30.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open and 1.5 emitter to base voltage, static, collector open

**Current Rating Per Characteristic:** 

70.00 milliamperes source cutoff current

Power Rating Per Characteristic:

900.0 milliwatts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

300.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

### Unit Of Measure:

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**Demilitarization:** 

No

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